

TLP321, -2, -4

(TLP321)

PROGRAMMABLE CONTROLLERS

DC-OUTPUT MODULE

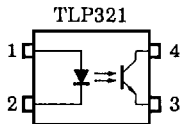
TELECOMMUNICATION

The TOSHIBA TLP321, -2 and -4 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode. The TLP321-2 offers two isolated channels in an eight lead plastic DIP package, while the TLP321-4 provides four isolated channels in a sixteen plastic DIP package.

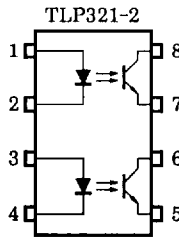
TLP321/-2/-4 have high V_{CEO} Voltage (V_{CEO}=80V).

- Collector-Emitter Voltage : 80V (Min.)
- Current Transfer Ratio : 50% (Min.)
Rank GB : 100% (Min.)
- Isolation Voltage : 5000Vrms (Min.)
- UL Recognized : UL1577, File No. E67349

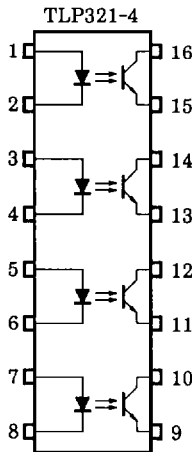
PIN CONFIGURATIONS (TOP VIEW)



1 : ANODE
2 : CATHODE
3 : EMITTER
4 : COLLECTOR

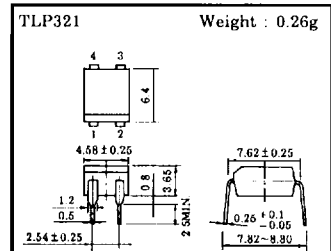


1, 3 : ANODE
2, 4 : CATHODE
5, 7 : EMITTER
6, 8 : COLLECTOR



1, 3, 5, 7 : ANODE
2, 4, 6, 8 : CATHODE
9, 11, 13, 15 : EMITTER
10, 12, 14, 16 : COLLECTOR

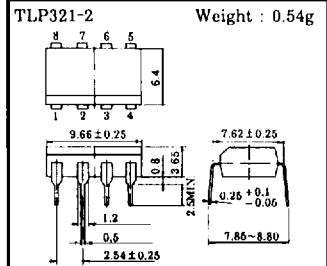
Unit in mm



JEDEC —

EIAJ —

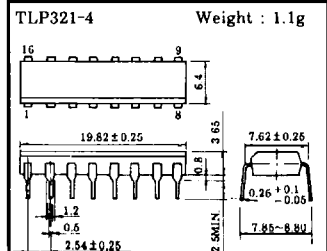
TOSHIBA 11-5B1



JEDEC —

EIAJ —

TOSHIBA 11-10C1



JEDEC —

EIAJ —

TOSHIBA 11-20A1

TLP321, -2, -4

(TLP321)

MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING		UNIT
			TLP321-1	TLP321-2, -4	
LED	Forward Current	I_F	60	50	mA
	Forward Current Derating	$\Delta I_F / ^\circ\text{C}$	-0.7 (Ta \geq 39°C)	-0.5 (Ta \geq 25°C)	mA / °C
	Pulse Forward Current	I_{FP}	1 (100 μ s pulse, 100pps)		A
	Reverse Voltage	V_R	5		V
	Junction Temperature	T_j	125		°C
DETECTOR	Collector-Emitter Voltage	V_{CEO}	80		V
	Emitter-Collector Voltage	V_{ECO}	7		V
	Collector Current	I_C	50		mA
	Collector Power Dissipation (1 Circuit)	P_C	150	100	mW
	Collector Power Dissipation Derating (1 Circuit, Ta \geq 25°C)	$\Delta P_C / ^\circ\text{C}$	-1.5	-1.0	mW / °C
	Junction Temperature	T_j	125		°C
	Storage Temperature Range	T_{stg}	-55~125		°C
Operating Temperature Range	T_{opr}	-55~100		°C	
Lead Soldering Temperature	T_{sol}	260 (10s)		°C	
Total Package Power Dissipation	R_T	250	150	mW	
Total Package Power Dissipation Derating (Ta \geq 25°C)	$\Delta P_T / ^\circ\text{C}$	-2.5	-1.5	mW / °C	
Isolation Voltage (Note 1)	BV_S	5000 (AC, 1 min., RH \leq 60%)		Vrms	

Note 1 : Device considered a two terminal device : LED side pins shorted together and DETECTOR side pins shorted together.

(TLP321)

TYPE	CLASSI- FICATION *1	CURRENT TRANSFER RATIO (%) (I_C / I_F)		MARKING OF CLASSIFICATION
		$I_F = 5\text{mA}, V_{CE} = 5\text{V}, T_a = 25^\circ\text{C}$		
		MIN.	MAX.	
TLP321	(None)	50	600	BLANK, Y, Y [■] , G, G [■] , B, B [■] , GB
	Rank Y	50	150	Y, Y [■]
	Rank GR	100	300	G, G [■]
	Rank BL	200	600	B, B [■]
	Rank GB	100	600	G, G [■] , B, B [■] , GB
TLP321-2	(None)	50	600	BLANK, GR, BL, GB
TLP321-4	Rank GB	100	600	GR, BL, GB

*1 : Ex. Rank GB : TLP321 (GB)

Note : Application type name for certification test, please use standard product type name, i.e.

TLP321 (GB) : TLP321

TLP321-2 (GB) : TLP321-2



TLP321, -2, -4

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INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 0.5\text{mA}$	80	—	—	V
	Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	$I_E = 0.1\text{mA}$	7	—	—	V
	Collector Dard Current	I_{CEO}	$V_{CE} = 48\text{V}$	—	10	100	nA
			$V_{CE} = 48\text{V}, T_a = 85^\circ\text{C}$	—	2	50	μA
	Capacitance (Collector to Emitter)	C_{CE}	$V = 0, f = 1\text{MHz}$	—	10	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I_C / I_F	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_{F(\text{sat})}$	$I_F = 1\text{mA}, V_{CE} = 0.4\text{V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 2.4\text{mA}, I_F = 8\text{mA}$	—	—	0.4	V
		$I_C = 0.2\text{mA}, I_F = 1\text{mA}$ Rank GB	—	0.2	—	
			—	—	0.4	

(TLP321)

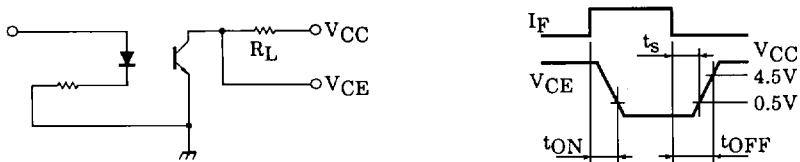
ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	C _S	V _S =0, f=1MHz	—	0.8	—	pF
Isolation Resistance	R _S	V _S =500V, R.H. ≤ 60%	5 × 10 ¹⁰	10 ¹⁴	—	Ω
Isolation Voltage	BV _S	AC, 1 minute	5000	—	—	Vrms
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Rise Time	t _r	V _{CC} = 10V I _C = 2mA R _L = 100Ω	—	2	—	μs
Fall Time	t _f		—	3	—	
Turn-on Time	t _{on}		—	3	—	
Turn-off Time	t _{off}		—	3	—	
Turn-on Time	t _{ON}	R _L = 1.9kΩ (Fig.1) V _{CC} = 5V, I _F = 16mA	—	2	—	μs
Storage Time	t _s		—	15	—	
Turn-off Time	t _{OFF}		—	25	—	

Fig.1 Switching Time Test Circuit

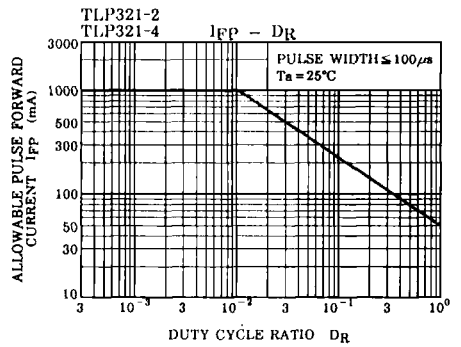
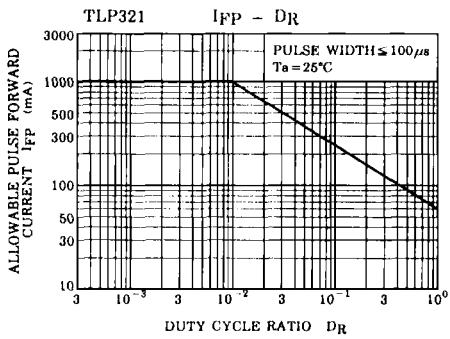
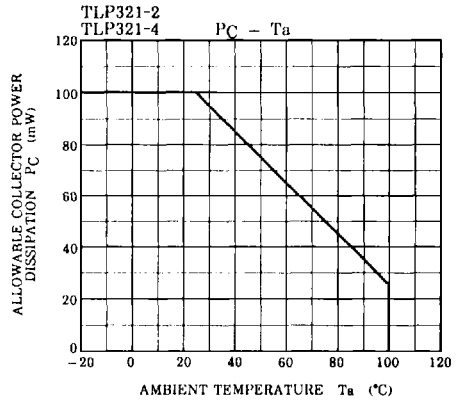
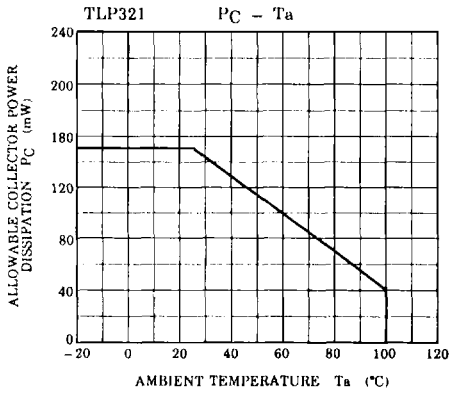
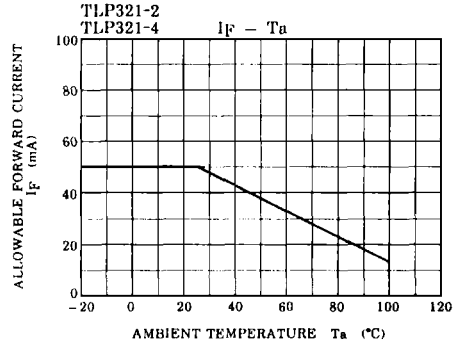
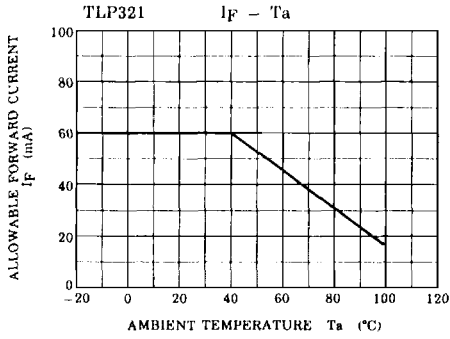


RECOMMENDED OPERATING CONDITIONS

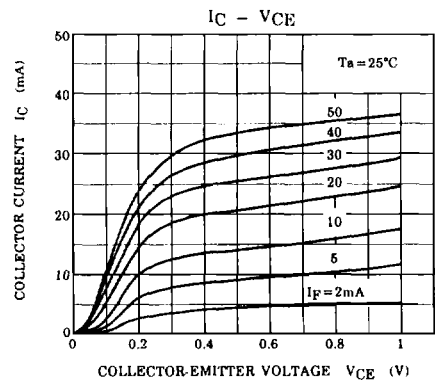
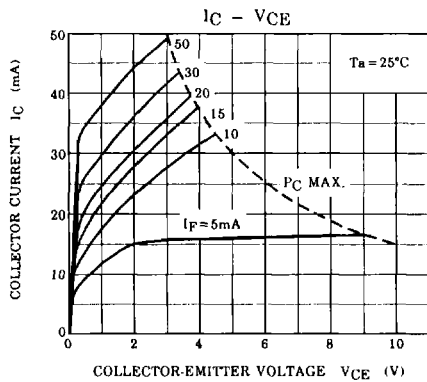
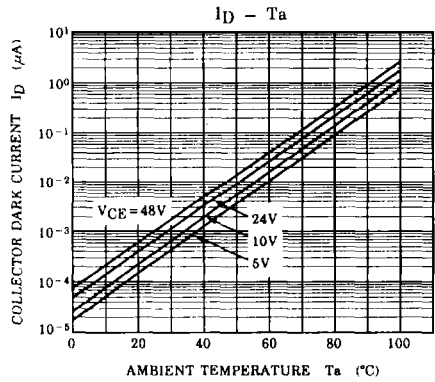
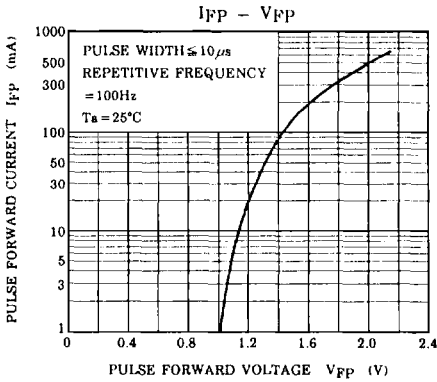
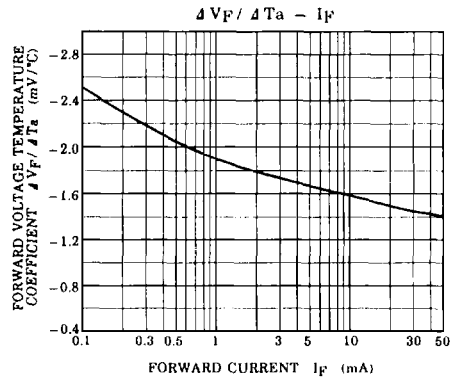
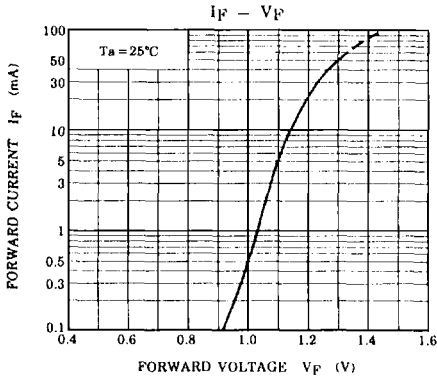
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{CC}	—	12	48	V
Forward Current	I _F	—	16	20	mA
Collector Current	I _C	—	1	10	mA
Operating Temperature	T _{opr}	-25	—	85	°C

TLP321, -2, -4

(TLP321)



(TLP321)



(TLP321)

